## NSN 5961-01-077-2947

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-077-2947 **Inclosure Material:** Metal **Overall Length:** 1.750 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches Thread Size: 0.375 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 repetitive peak reverse voltage, peak total value and 200.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 157.00 amperes forward current, average and 100.00 amperes forward current, average of standard range **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 80372-775194a0153 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No